PMEG2002ESF

20 V, 0.2 A low VF MEGA Schottky barrier rectifier

8 October 2013 Product data sheet

1. General description

Planar Maximum Efficiency General Application (MEGA) Schottky barrier rectifier with an integrated guard ring for stress protection in a DSN0603-2 (SOD962-2) leadless ultra small Surface-Mounted Device (SMD) package.

2. Features and benefits

- Average forward current $I_{F(AV)}$ ≤ 0.2 A
- Reverse voltage V_R ≤ 20 V
- Low forward voltage typ. V_F 310 mV
- Low reverse current typ. I_R 0.88 µA
- Ultra small and leadless SMD package
- Package height typ. 0.3 mm

3. Applications

- Low voltage rectification
- High efficiency DC-to-DC conversion
- Switch mode power supply
- Low power consumption applications
- Ultra high-speed switching
- LED backlight for mobile application

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
$I_{F(AV)}$	average forward current	δ = 0.5 ; f = 20 kHz; T_{sp} ≤ 125 °C; square wave		-	-	0.2	A
		δ = 0.5 ; f = 20 kHz; T_{amb} ≤ 115 °C; square wave	[1]	-	-	0.2	A
V_R	reverse voltage	T_j = 25 °C		-	-	20	V
V_F	forward voltage	I_F = 10 mA; pulsed; t_p ≤ 300 µs; δ ≤ 0.02 ; T_j = 25 °C		-	310	380	mV
I_R	reverse current	V_R = 10 V; T_j = 25 °C		-	0.37	-	µA

[1] Device mounted on a ceramic Printed-Circuit Board (PCB), Al_2O_3, standard footprint.

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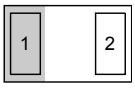
5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode[1]	 Transparent top view **DSN0603-2 (SOD962-2)**	 *sym001*
2	A	anode		

[1] The marking bar indicates the cathode.

6. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
PMEG2002ESF	DSN0603-2	Leadless ultra small package; 2 terminals; body 0.6 x 0.3 x 0.3 mm	SOD962-2

7. Marking

Table 4. Marking codes

Type number	Marking code
PMEG2002ESF	E

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V_R	reverse voltage	T_j = 25 °C		-	20	V
I_F	forward current	$T_{sp} \leq 120$ °C		-	0.28	A
$I_{F(AV)}$	average forward current	$\delta = 0.5$; f = 20 kHz; $T_{sp} \leq 125$ °C; square wave		-	0.2	A
		$\delta = 0.5$; f = 20 kHz; $T_{amb} \leq 115$ °C; square wave	[1]	-	0.2	A
I_{FRM}	repetitive peak forward current	$t_p \leq 1$ ms; $\delta \leq 0.25$		-	1	A
I_{FSM}	non-repetitive peak forward current	t_p = 8 ms; $T_{j(init)}$ = 25 °C; square wave		-	4.5	A
P_{tot}	total power dissipation	$T_{amb} \leq 25$ °C	[2]	-	325	mW

Symbol	Parameter	Conditions		Min	Max	Unit
			[3]	-	525	mW
			[1]	-	950	mW
T_j	junction temperature			-	125	°C
T_{amb}	ambient temperature			-55	125	°C
T_{stg}	storage temperature			-65	150	°C

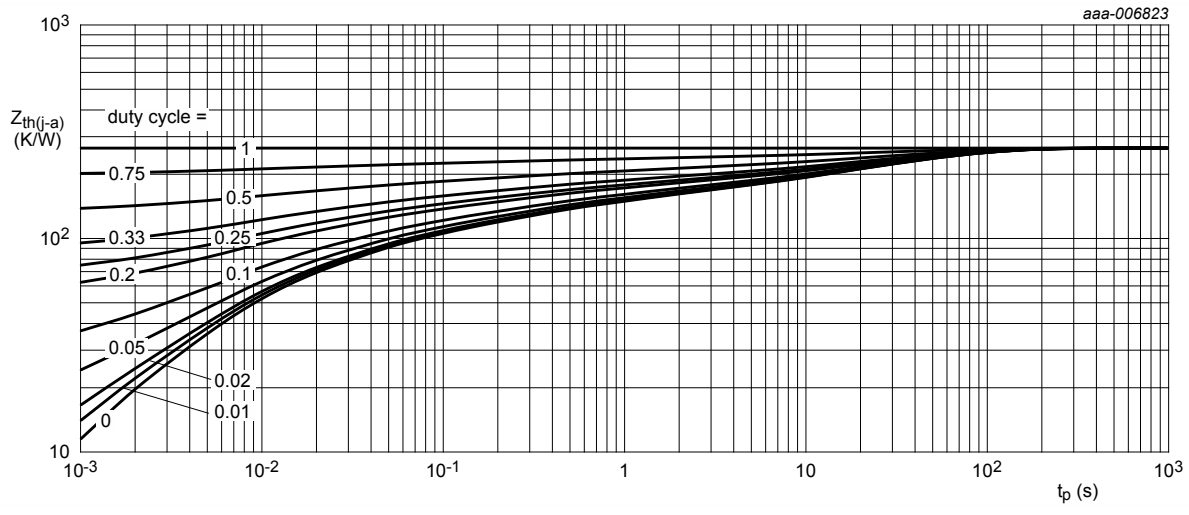
[1] Device mounted on a ceramic Printed-Circuit Board (PCB), Al_2O_3, standard footprint.
[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for anode and cathode 1 cm^2 each.

9. Thermal characteristics

Table 6. Thermal characteristics

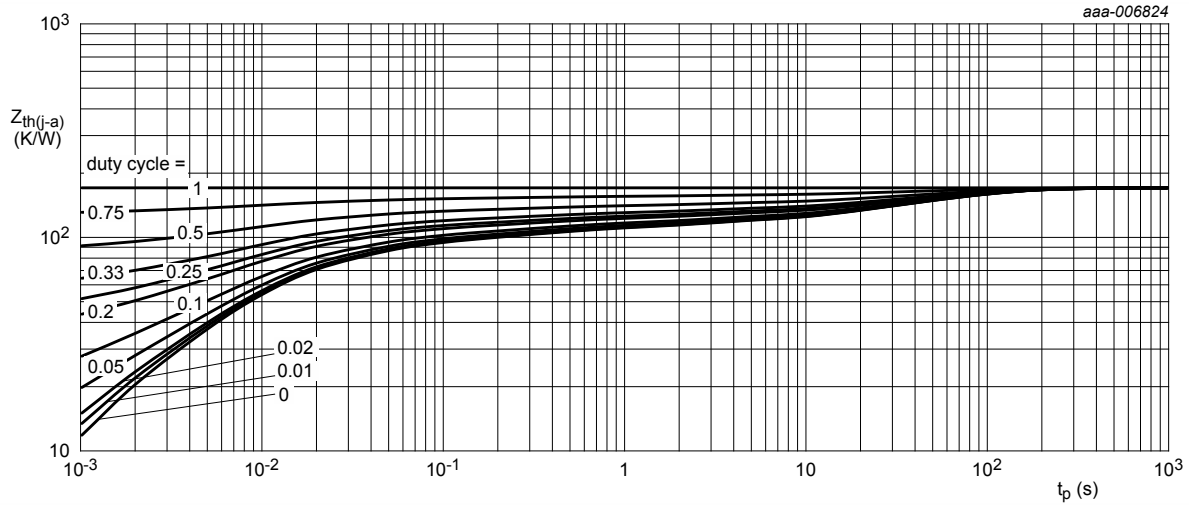
Symbol	Parameter	Conditions		Min	Typ	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1][2]	-	-	310	K/W
			[1][3]	-	-	190	K/W
			[1][4]	-	-	105	K/W
$R_{th(j-sp)}$	thermal resistance from junction to solder point		[5]	-	-	40	K/W

[1] For Schottky barrier diodes thermal runaway has to be considered, as in some applications the reverse power losses P_R are a significant part of the total power losses.
[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for anode and cathode 1 cm^2 each.
[4] Device mounted on a ceramic PCB, Al_2O_3, standard footprint.
[5] Soldering point of cathode tab.



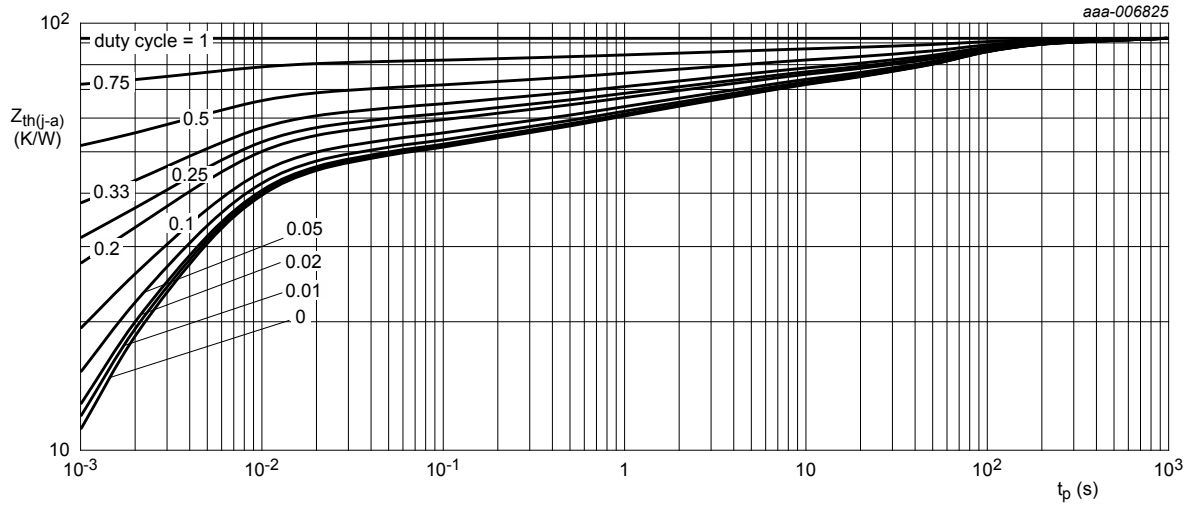
FR4 PCB, standard footprint

Fig. 1. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB, mounting pad for anode and cathode 1 cm^2 each

Fig. 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



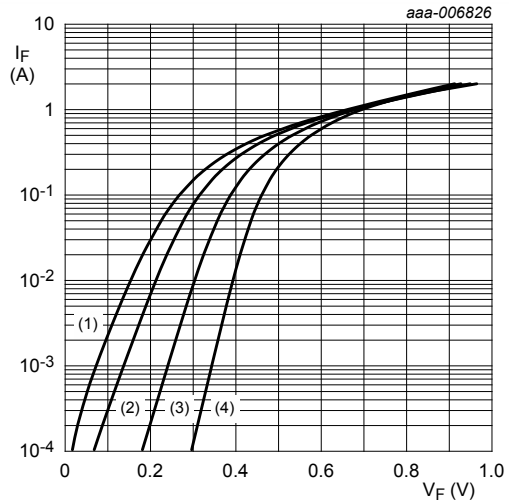
Ceramic PCB, Al_2O_3, standard footprint

Fig. 3. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

10. Characteristics

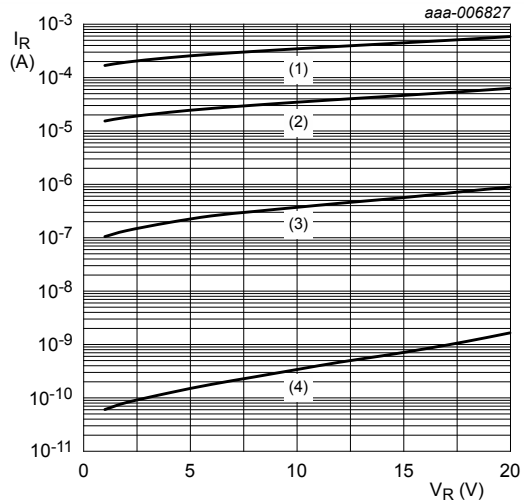
Table 7. Characteristics

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
V_F	forward voltage	I_F = 0.1 mA; pulsed; $t_p \leq 300$ µs; $\delta \leq 0.02$; T_j = 25 °C		-	185	250	mV
		I_F = 1 mA; pulsed; $t_p \leq 300$ µs; $\delta \leq 0.02$; T_j = 25 °C		-	245	320	mV
		I_F = 10 mA; pulsed; $t_p \leq 300$ µs; $\delta \leq 0.02$; T_j = 25 °C		-	310	380	mV
		I_F = 100 mA; pulsed; $t_p \leq 300$ µs; $\delta \leq 0.02$; T_j = 25 °C		-	390	450	mV
		I_F = 200 mA; pulsed; $t_p \leq 300$ µs; $\delta \leq 0.02$; T_j = 25 °C		-	435	490	mV
I_R	reverse current	V_R = 6 V; T_j = 25 °C		-	0.26	1.5	µA
		V_R = 10 V; T_j = 25 °C		-	0.37	-	µA
		V_R = 20 V; T_j = 25 °C		-	0.88	3.5	µA
C_d	diode capacitance	V_R = 1 V; f = 1 MHz; T_j = 25 °C		-	25	-	pF
		V_R = 10 V; f = 1 MHz; T_j = 25 °C		-	9	-	pF
t_{rr}	reverse recovery time	I_F = 200 mA; I_R = 200 mA; $I_{R(meas)}$ = 40 mA; T_j = 25 °C		-	1.9	-	ns



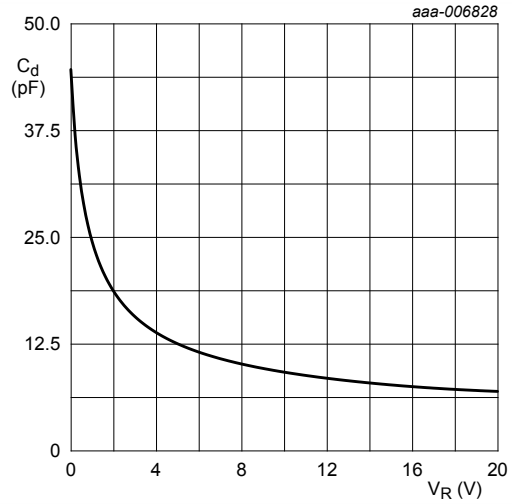
(1) T_j = 125 °C
(2) T_j = 85 °C
(3) T_j = 25 °C
(4) T_j = −40 °C

Fig. 4. Forward current as a function of forward voltage; typical values



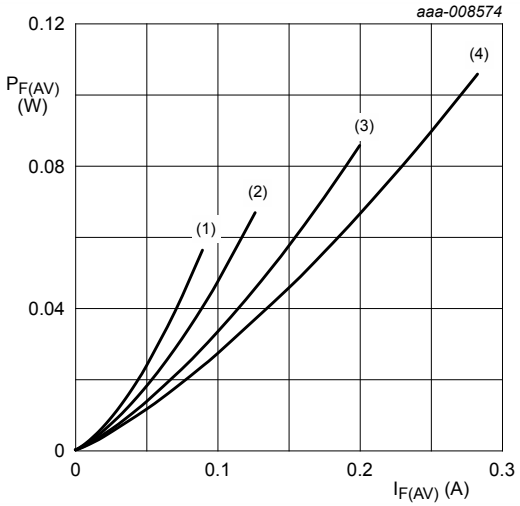
(1) T_j = 125 °C
(2) T_j = 85 °C
(3) T_j = 25 °C
(4) T_j = −40 °C

Fig. 5. Reverse current as a function of reverse voltage; typical values



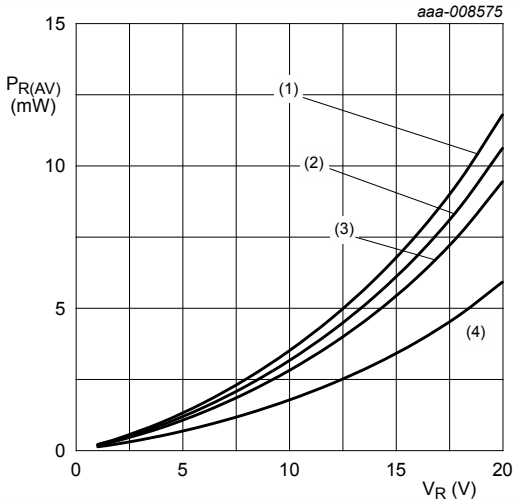
f = 1 MHz; T_{amb} = 25 °C

Fig. 6. Diode capacitance as a function of reverse voltage; typical values



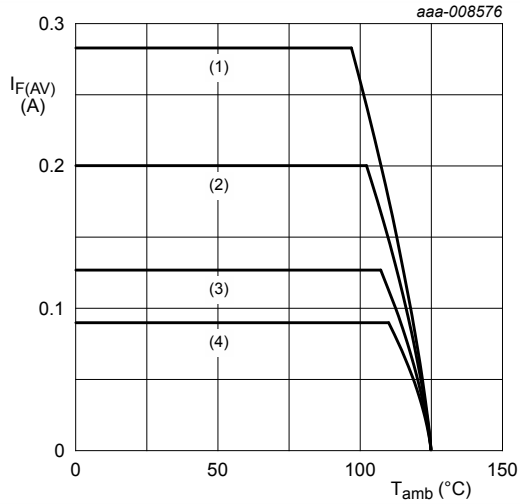
T_j = 125 °C
(1) δ = 0.1
(2) δ = 0.2
(3) δ = 0.5
(4) δ = 1

Fig. 7. Average forward power dissipation as a function of average forward current; typical values



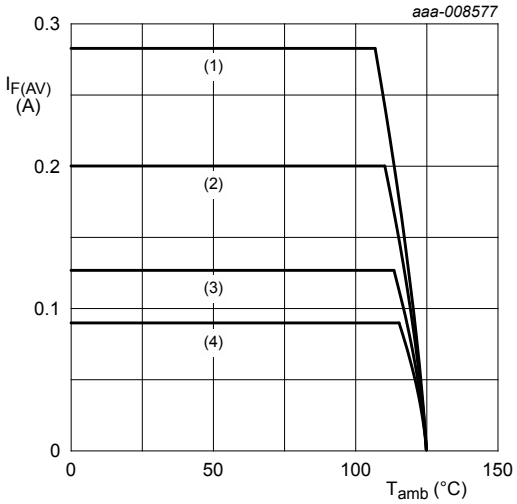
T_j = 125 °C
(1) δ = 1 (DC)
(2) δ = 0.9; f = 20 kHz
(3) δ = 0.8; f = 20 kHz
(4) δ = 0.5; f = 20 kHz

Fig. 8. Average reverse power dissipation as a function of reverse voltage; typical values



FR4 PCB, standard footprint
T_j = 125 °C
(1) δ = 1
(2) δ = 0.5
(3) δ = 0.2
(4) δ = 0.1

Fig. 9. Average forward current as a function of ambient temperature; typical values



FR4 PCB, mounting pad for anode and cathode 1 cm^2 each

T_j = 125 °C

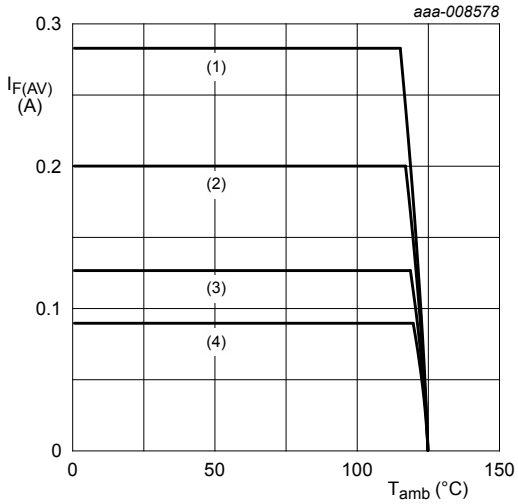
(1) δ = 1

(2) δ = 0.5

(3) δ = 0.2

(4) δ = 0.1

Fig. 10. Average forward current as a function of ambient temperature; typical values



Ceramic PCB, Al_2O_3, standard footprint

T_j = 125 °C

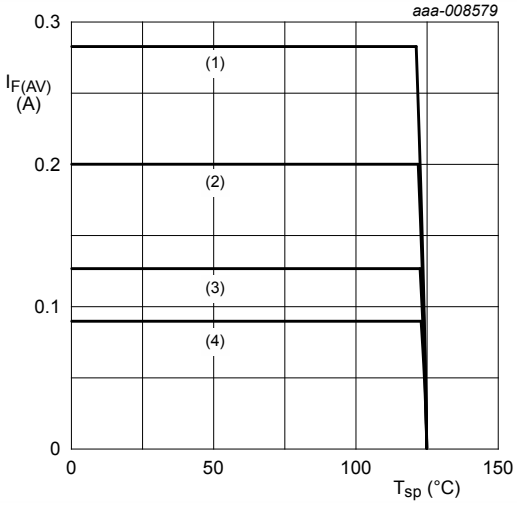
(1) δ = 1

(2) δ = 0.5

(3) δ = 0.2

(4) δ = 0.1

Fig. 11. Average forward current as a function of ambient temperature; typical values



T_j = 125 °C

(1) δ = 1

(2) δ = 0.5

(3) δ = 0.2

(4) δ = 0.1

Fig. 12. Average forward current as a function of solder point temperature; typical values

11. Test information

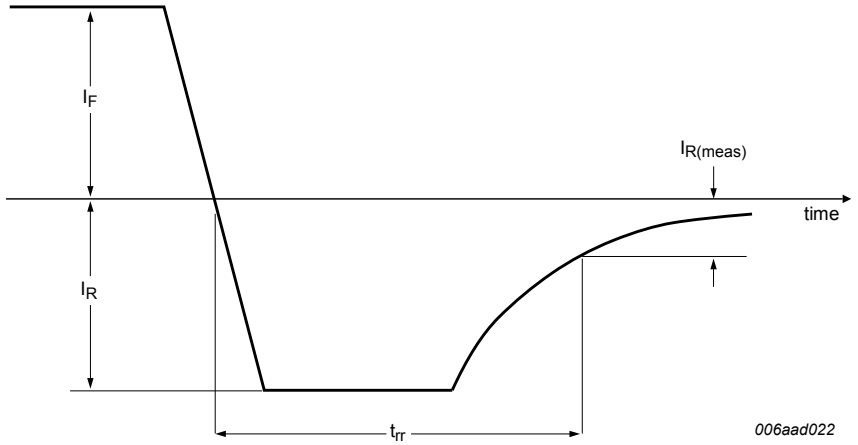


Fig. 13. Reverse recovery definition

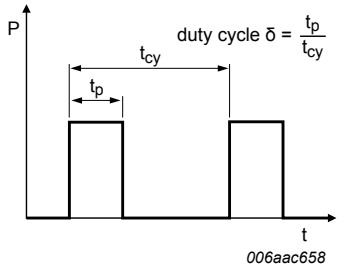
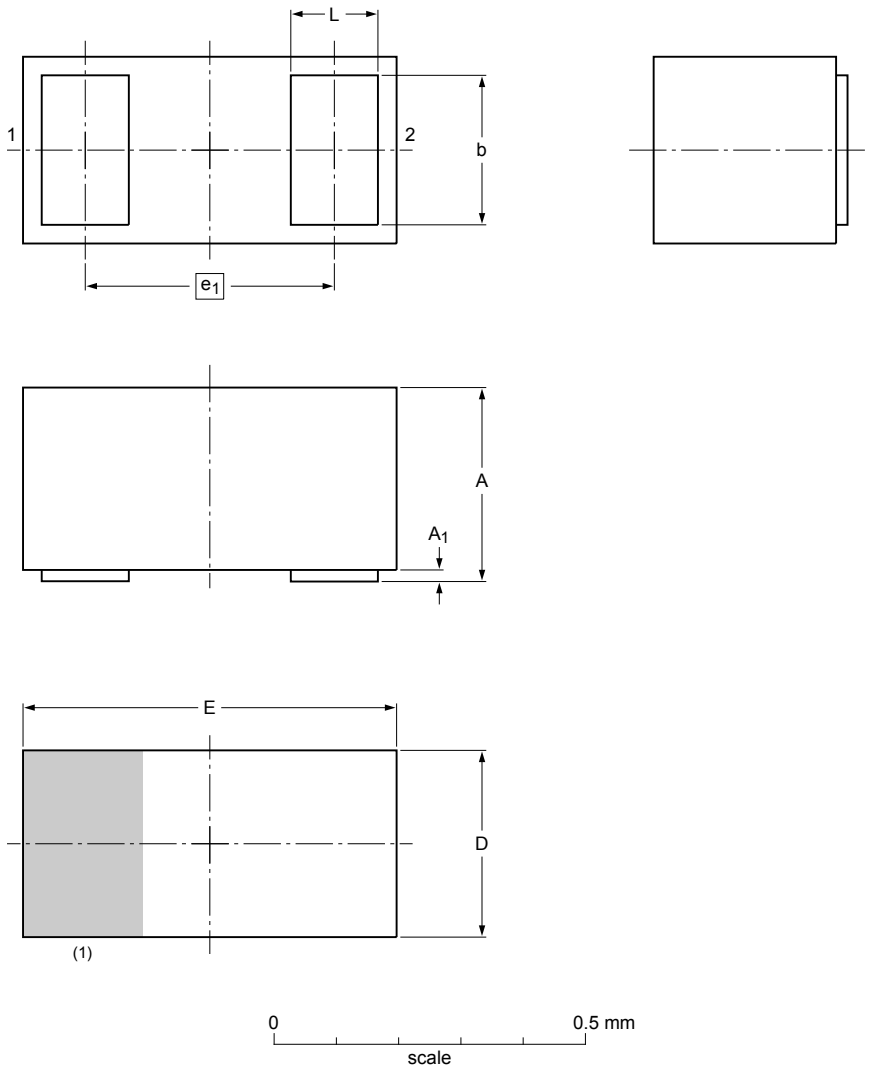


Fig. 14. Duty cycle definition

The current ratings for the typical waveforms are calculated according to the equations: $I_{F(AV)} = I_M \times \delta$ with I_M defined as peak current, $I_{RMS} = I_{F(AV)}$ at DC, and $I_{RMS} = I_M \times \sqrt{\delta}$ with I_{RMS} defined as RMS current.

12. Package outline

Leadless ultra small package; 2 terminals; body 0.6 x 0.3 x 0.3 mm **SOD962-2**



Dimensions (mm are the original dimensions)

Unit		A	A_1	b	D	E	e_1	L
mm	max	0.32	0.03	0.25	0.325	0.625		0.15
	nom						0.4	
	min	0.28		0.23	0.275	0.575		0.13

Note
1. The marking bar indicates the cathode.

sod962-2_po

Outline version	References				European projection	Issue date
	IEC	JEDEC	JEITA			
SOD962-2						~~13-07-12~~ 13-07-17

Fig. 15. Package outline DSN0603-2 (SOD962-2)

13. Soldering

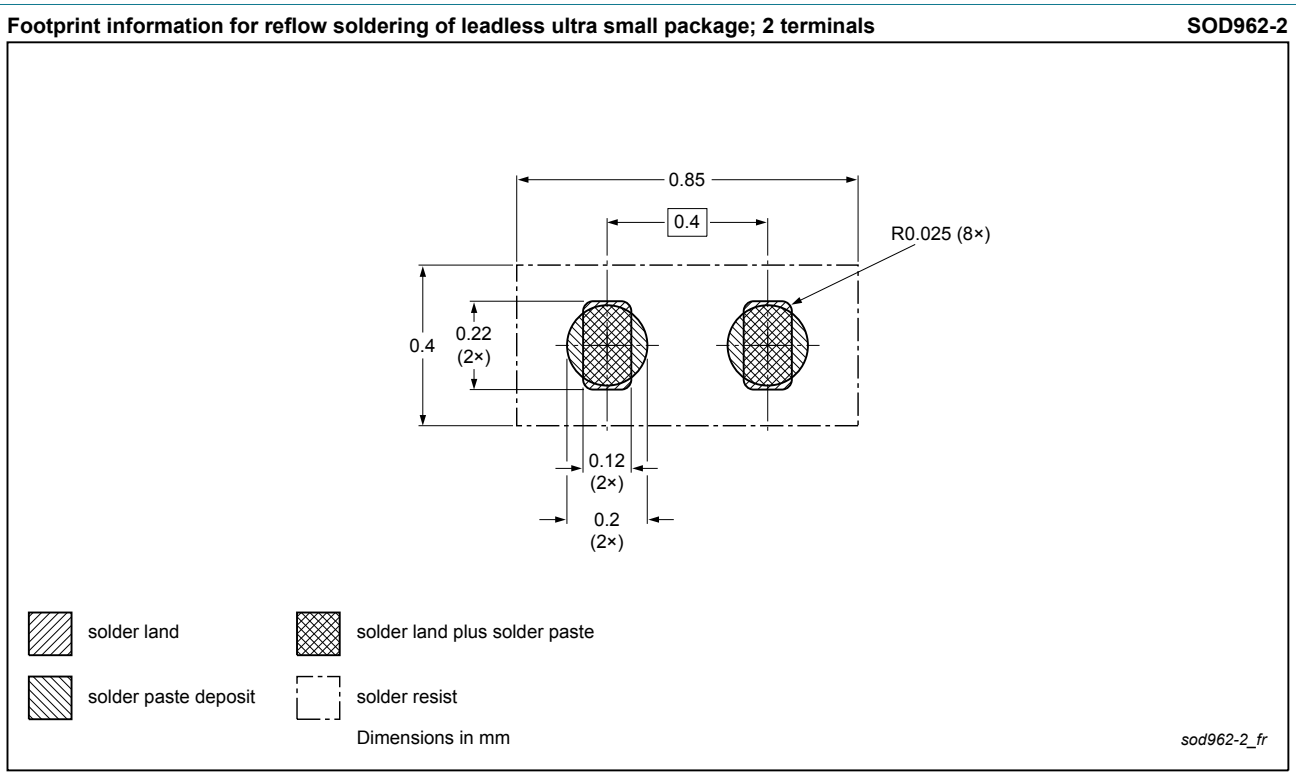


Fig. 16. Reflow soldering footprint for DSN0603-2 (SOD962-2)

14. Revision history

Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PMEG2002ESF v.2	20131008	Product data sheet	-	PMEG2002ESF v.1
Modifications:	• Product status changed			
PMEG2002ESF v.1	20130301	Objective data sheet	-	-

15. Legal information

15.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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